Calculation of parameters of Heine and Abarenkov model potential for bcc crystals

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Abstract

Parameters of Heine and Abarenkov model potential (HAP) have been computed in this paper for sixteen body centered cubic (bcc) closed pack crystals. From the minimization of structure dependent energy of the pure crystal the inter-relation between the two parameters is first determined. Calculation uses pseudopotential technique with nine different exchange and correlation functions (ECF) and either only available experimental value of vacancy formation energy (VFE) or that obtained from an empirical relation based on other experimental parameters (Melting temperature, cohesive energy or activation energy) as tool. The variation of VFE with one parameter of HAP and different ECF show sharp fall in VFE near very small value of it after which it shows constancy for all bcc crystals. Comparison is made with parameter of Ashcroft model also. For increase in valency this parameter of HAP increases and show distinct different curves.

KEYWORDS

Point defect, vacancy, Heine and Abarenkov model pseudopotential, bcc crystal, exchange and correlation function.

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1. Introduction

Here I shall use a simplified way of pseudopotential approach which is comparatively easier to get some insight into some bcc crystals. This is for recent studies of the mechanism of melting [1-2] by considering the role of surfaces with regard to the concentration and migration of vacancies, provides valuable input for this type of work. Necessity of this work is due to the fact that a database for fcc and hcp crystals was demonstrated using ab initio calculations by Angsten et. al. [3] and seven interatomic potentials were discussed by Li et. al. [4].

The two parameters $(A, r_c)_{HA}$ of simple Heine and Abarenkov model pseudopotential (henceforth called HAP) is used for this purpose. The Fourier transform of it is given by [5]

$$\omega(q) = \frac{4\pi A}{\Omega q^3} (qr_c cosqr_c - sinqr_c) - \frac{4\pi z e^2}{\Omega q^2} cosqr_c$$
(1)

Here z is the valency, Ω the atomic volume, e the electronic charge, and q the wave number. Earlier these two values calculated using fittings to several experimental values of atomic properties, viz. phonon dispersion curves, resistivity, elastic constants, lattice parameter, etc. But here only the experimental value of vacancy formation energy (VFE) will be used for the calculation.

2. Results and discussions

The expression for VFE uses pseudopotential method [6-7] and computation uses integration and summation. The integration over quasi-continuous wave numbers \vec{q} uses Gauss-



Legendre quadrature method within the limit from 0 to 1 in 100 divisions and Gauss-Laguerre quadrature integration in the limit from 1 to infinity [8].

 $\int_0^{\infty} \rightarrow \int_0^1 \text{Gauss} - \text{Lagendre} + \int_1^{\infty} \text{Gauss} - \text{Laguerre} \qquad -(2)$ The discrete sum over lattice wave numbers defined as $\vec{q}_0 = \frac{m_1}{N_1} q_1 + \frac{m_2}{N_2} \vec{q}_2 + \frac{m_3}{N_3} \vec{q}_3$ where the maximum value of $\frac{m_i}{N_i} = 14$ with i=1,2,3 and the lattice wave numbers are generated in the cubic Brillouin zone with the reciprocal lattice vectors respectively as $\vec{q}_1 = \frac{2\pi}{a}(\hat{j} + \hat{k}), \ \vec{q}_2 = \frac{2\pi}{a}(\hat{k} + \hat{i})$ and $\vec{q}_3 = \frac{2\pi}{a}(\hat{i} + \hat{j}), \ (\hat{i}, \hat{j}, \hat{k})$ being unit vectors along three coordinates. The input parameters used in this calculation are lattice constant a and experimental or theoretical mean value of VFE. The necessity of (VFE)_{theo} is due to the fact that in most of the cases the experimental value of VFE is not available and so (VFE)_{theo} is determined from an empirical relation among the melting temperature (T_m) , the cohesive energy (E_{coh}) and the activation energy for self diffusion (Q_0) .



Figure 1 : $E_F^{1\nu} - A$ plot for Lithium (Li) and Sodium (Na) type bcc metals



Figure 2 : $E_F^{1\nu} - A$ plot for Potassium (K) and Rubidium (Rb) type bcc metals



Figure 3 : $E_F^{1\nu} - A$ plot for Cesium (Cs) and Barium (Ba) type bcc metals



Figure 4 : $E_F^{1\nu} - A$ plot for Iron (Fe) and Chromium (Cr) type bcc metals



Figure 5 : $E_F^{1\nu} - A$ plot for Molybdenum (Mo) and Tungsten (W) type bcc metals



Figure 6 : $E_F^{1\nu} - A$ plot for Vanadium (V) and Niobium (Nb) type bcc metals



Figure 7 : $E_F^{1\nu} - A$ plot for Tantalum (Ta) and Thallium (Tl) type bcc metals



Figure 8 : $E_F^{1\nu} - A$ plot for Europium (Eu) and Zirconium (Zr) type bcc metals

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I	nput	paran	neters [1 F	Rydbe	rg = 13	.605 eV] and [1	Atomic	Unit (A	AU) = 0	.0529177 nm]
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Atomic number	Configuratior	Valency	Lattice Constant (nm) ^a	Vasisth parame	a-Singwi ters in au	T _m (K) ^a	E _{coh} (eV) ^a	$\begin{array}{c} Q_0 \\ (eV)^b \end{array}$	(VFE) _{exp} (eV)	(VFE) _{theo} theoretical range in (eV)
3	He2s ¹	1	0.3491	1.00529	0.29979	453.7	1.63	0.55 0.585	$0.34^{c} 0.4^{c} 0.48^{c}$	0.302-0.489
11	Ne3s ¹	1	0.4225	1.07771	0.2846	371	1.113	0.499 0.438	$\begin{array}{c} 0.36^{c} 0.39^{c} 0.42^{c} \\ 0.35^{d} \end{array}$	0.24-0.334
19	Ar4s ¹	1	0.5225	1.16737	0.26925	336.3	0.934	0.418 0.409	$0.39^{c} 0.3^{c} 0.31^{d}$	0.23-0.28
37	Kr5s ¹	1	0.5585	1.19566	0.26981	312.6	0.852	$0.408 \\ 0.409$	0.27 ^{c,d}	0.224-0.261
55	Xe6s ¹	1	0.6045	1.23419	0.2605	301.6	0.804	3.998	$0.28^{c} 0.26^{d}$	0.241-2.199
56	Xe6s ²	2	0.502	1.14962	0.27321	1002	1.9			0.57-0.835
26	Ar3d ⁶ 4s ²	2	0.287	0.93847	0.31221	1811	4.28	2.658 2.488	1.6 ^e	1.284-1.509
24	Ar3d ⁴ 4s ²	2	0.288	0.93937	0.31294	2133	4.1	3.196 4.572	$2.0^{\rm f} 2.27^{\rm f} 2.08^{\rm f}$	1.23-2.51
42	Kr4d ⁵ 5s ¹	2	0.315	0.97098	0.30512	2895	6.82	3.998 3.997	$2.24^d \ 3.0^f \ 3.2^f$	2.046-2.413
74	Xe4f ¹⁴ 5d ² 6s ²	2	0.316	0.9713	0.30548	3695	8.9	6.076	$\begin{array}{c} 3.15^{d} \ 4.0^{f} \\ 4.1^{f} \ 3.6 \ -4.0^{f} \end{array}$	2.670-3.34
23	Ar3d ³ 4s ²	3	0.303	0.95586	0.30939	2202	5.31	4.58 4.083	2.2^{f}	1.593-2.519
41	Kr4d ⁴ 5s ¹	3	0.33	0.98576	0.30406	2750	7.57	4.163 4.164	$2.04^{\rm d} \ 2.6^{\rm f} \\ 2.7-3.0^{\rm f}$	2.271-2.292
73	Xe4f ¹⁴ 5d ² 6s ²	3	0.33	0.98576	0.30406	3293	8.1	4.28 4.281	$\begin{array}{c} 2.9^{\rm d}2.8^{\rm f} \\ 2.9^{\rm f}3.1^{\rm f} \end{array}$	2.354-2.744
81	Xe4f ¹⁴ 5d ² 6s ²	3	0.387	1.04372	0.29327	577	1.88	6.639		0.48-3.651
63	Xe4f ⁷ 5d ⁰ 6s ²	3	0.458	1.11056	0.28079	1091	1.86	1.489		0.558-0.909
40	Kr4d ² 5s ²	4	0.361	1.01502	0.29717	2128	6.25	0.85 0.88	1.75 ^d	0.468-1.875
	Atomic number 3 11 19 37 55 56 26 24 42 74 42 74 23 41 73 81 63 40	Atomic number Configuration 3 He2s ¹ 11 Ne3s ¹ 19 Ar4s ¹ 37 Kr5s ¹ 55 Xe6s ¹ 56 Xe6s ² 26 Ar3d ⁶ 4s ² 42 Kr4d ⁵ 5s ¹ 74 Xe4f ¹⁴ 5d ² 6s ² 23 Ar3d ³ 4s ² 41 Kr4d ⁴ 5s ¹ 73 Xe4f ¹⁴ 5d ² 6s ² 81 Xe4f ¹⁴ 5d ² 6s ² 40 Kr4d ² 5s ²	Atomic number Configuration/Valency 3 He2s ¹ 1 11 Ne3s ¹ 1 19 Ar4s ¹ 1 37 Kr5s ¹ 1 55 Xe6s ¹ 1 56 Xe6s ² 2 26 Ar3d ⁶ 4s ² 2 24 Ar3d ⁴ 4s ² 2 42 Kr4d ⁵ 5s ¹ 2 74 Xe4f ¹⁴ 5d ² 6s ² 2 23 Ar3d ³ 4s ² 3 41 Kr4d ⁵ 5s ¹ 3 73 Xe4f ¹⁴ 5d ² 6s ² 3 81 Xe4f ¹⁴ 5d ² 6s ² 3 63 Xe4f ⁷ 5d ⁰ 6s ² 3 40 Kr4d ² 5s ² 4	Atomic numberConfiguration ValencyLattice Constant (nm)a3He2s11 0.3491 11Ne3s11 0.4225 19Ar4s11 0.5225 37Kr5s11 0.5225 37Kr5s11 0.5225 37Kr5s11 0.5225 37Kr5s11 0.5225 37Kr5s11 0.6045 56Xe6s22 0.502 26Ar3d ⁶ 4s22 0.287 24Ar3d ⁴ 4s22 0.288 42Kr4d ⁵ 5s12 0.315 74Xe4f ¹⁴ 5d ² 6s ² 2 0.316 23Ar3d ³ 4s23 0.303 41Kr4d ⁴ 5s13 0.33 73Xe4f ¹⁴ 5d ² 6s ² 3 0.387 63Xe4f ⁷ 5d ⁰ 6s ² 3 0.458 40Kr4d ² 5s ² 4 0.361	Atomic numberConfiguration/alencyLattice Constant (nm)aVasisth parame3He2s11 0.3491 1.00529 11Ne3s11 0.4225 1.07771 19Ar4s11 0.5225 1.16737 37Kr5s11 0.5585 1.19566 55Xe6s11 0.6045 1.23419 56Xe6s22 0.502 1.14962 26Ar3d ⁶ 4s22 0.287 0.93847 24Ar3d ⁴ 4s22 0.288 0.93937 42Kr4d ⁵ 5s12 0.315 0.97098 74Xe4f ¹⁴ 5d ² 6s23 0.303 0.95586 41Kr4d ⁴ 5s13 0.33 0.98576 81Xe4f ¹⁴ 5d ² 6s23 0.458 1.11056 40Kr4d ² 5s24 0.361 1.01502	Atomic numberConfiguration/valencyLattice Constant (nm)aVasistha-Singwi parameters in au3He2s110.34911.005290.2997911Ne3s110.42251.077710.284619Ar4s110.52251.167370.2692537Kr5s110.55851.195660.2698155Xe6s110.60451.234190.260556Xe6s220.5021.149620.2732126Ar3d ⁶ 4s220.2880.939370.3122124Ar3d ⁴ 4s220.2880.939370.3129442Kr4d ⁵ 5s120.3160.97130.3054823Ar3d ³ 4s230.3030.955860.3093941Kr4d ⁴ 5s130.330.985760.3040673Xe4f ¹⁴ 5d ² 6s ² 30.4581.110560.2807940Kr4d ² 5s ² 40.3611.015020.29717	Atomic numberConfiguration valencyLattice Constant (nm)aVasistha-Singwi parameters in au T_m (K)a3He2s110.34911.005290.29979453.711Ne3s110.42251.077710.284637119Ar4s110.52251.167370.26925336.337Kr5s110.55851.195660.26981312.655Xe6s110.60451.234190.2605301.656Xe6s220.5021.149620.27321100226Ar3d ⁶ 4s220.2870.938470.31221181124Ar3d ⁴ 4s220.2880.939370.31294213342Kr4d ⁵ 5s120.3160.97130.30548369523Ar3d ³ 4s230.3030.955860.30939220241Kr4d ⁴ 5s130.330.985760.30406329381Xe4f ¹⁴ 5d ² 6s ² 30.4581.10560.28079109140Kr4d ² 5s ² 40.3611.015020.297172128	Atomic numberConfiguration valencyLattice Constant (nm)aVasistha-Singwi parameters in au T_m (K)a E_{coh} (eV)a3He2s110.34911.005290.29979453.71.6311Ne3s110.42251.077710.28463711.11319Ar4s110.52251.167370.26925336.30.93437Kr5s110.55851.195660.26981312.60.85255Xe6s110.60451.234190.2605301.60.80456Xe6s220.5021.149620.2732110021.926Ar3d ⁶ 4s220.2880.939370.3129421334.142Kr4d ⁵ 5s120.3150.970980.3051228956.8274Xe4f ¹⁴ 5d ² 6s ² 20.3160.97130.3040627507.5773Xe4f ¹⁴ 5d ² 6s ² 30.330.985760.3040632938.181Xe4f ¹⁴ 5d ² 6s ² 30.3871.043720.293275771.8863Xe4f ⁷ 5d ⁶ 6s ² 30.4581.10560.2807910911.8640Kr4d ² 5s ² 40.3611.015020.2971721286.25	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $

^aRef. [10]; ^bRef. [11]; ^cRef. [12]; ^dRef. [1]; ^eRef. [13]; ^fRef. [14].

In the first step, the two parameters $(A, r_c)_{HA}$ of HAP suggest a minimization of structure dependent energy of the pure crystal and yield a relation $A = \frac{ze^2}{r_c}$. The value of VFE is

computed for different values of parameter A of HAP and it is now plotted for nine ECFs [9] for sixteen different body centered cubic (bcc) closed pack crystals, viz. lithium (Li), sodium (Na), potassium (K), rubidium (Rb), cesium (Cs), barium (Ba), iron (Fe), chromium (Cr), molybdenum (Mo), tungsten (W), vanadium (V), niobium (Nb), tantalum (Ta), thallium (Tl), europium (Eu) and zirconium (Zr). There is a sharp fall in VFE near very small value of A in the VFE-A plot and with increase in A VFE shows constancy for all bcc crystals as shown in figure 1 to figure 8.

The value of A and hence r_c are determined from fitting to all the experimental values of $(VFE)_{exp}$ or theoretical mean value of $(VFE)_{theo}$. Thus a plot of VFE- r_c with fixed value of A will be expected to show definite convergence. The theoretical estimation using an empirical relation [8] is also very close to ab initio calculations by Angsten et. al. [3]. This is shown in the table 1. However there is a systematic change in the fitted value of A for every bcc metal from one ECF to other so also there is a change in the value of r_c from one ECF to other.

	ΔA for different ECF in eV	Δr_c for different ECF in nm	Ashcroft (r	(nm)	Heine-Abarenkov $(A, r_c)_{HA}$ parameters				
Metal			$(r_c)_{Ash}^{a}$	Mean $(r_c)_{Ash}^{b}$	Mean (r _c) _{HA} nm	Other $(r_c)_{HA}$	Mean (A) _{HA} eV	Other $(A)_{HA}$ eV	
Li	2.03	0.023	0.06-0.11	0.071 ^b	0.1248		11.5626		
Na	1.10	0.022	0.09	0.090^{b}	0.1616		8.9245		
K	0.68	0.022	0.12	0.117^{b}	0.2135		6.7499		
Rb	0.81	0.029	0.11-0.14	0.126 ^b	0.2215		6.5085		
Cs	0.68	0.030	0.11-0.16	0.157 ^b	0.2469		5.8383		
Ba	0.83	0.007		0.124 ^b	0.2055		14.0172		
Fe	3.80	0.006		0.061 ^c	0.0959		30.0761		
Cr	3.06	0.016		0.063 ^d	0.1022	0.13 ^e	28.2060	21.77 ^e	
Mo	1.67	0.005		0.074 ^d	0.1265	0.11 ^e	22.7786	31.29 ^e	
W	0.89	0.003		0.077^{d}	0.1337	0.11 ^e	21.5442	31.29 ^e	
V	6.02	0.005		0.068^{d}	0.0980	$0.08^{\rm e}$	44.1535	44.22 ^e	
Nb	4.36	0.005		0.079 ^d	0.1168	0.11 ^e	37.0047	23.13 ^e	
Та	3.76	0.004		0.079^{d}	0.1182	0.11 ^e	36.5779	23.81 ^e	
Tl	1.56	0.003		0.096 ^d	0.1550		27.8773		
Eu	2.27	0.005		0.118 ^d	0.1713		25.2297		
Zr	5.49	0.004		0.081 ^d	0.1216		47.4232		

Input parameters [1 Rydberg = 13.605 eV] and [1 Atomic Unit (AU) = 0.0529177 nm]

^aRef. [15]; ^bRef. [16]; ^cRef. [13]; ^dRef. [14]; ^eRef. [17].

Since the difference is about 10% so the variation of HAP parameters A and r_c for all nine ECFs are not shown but only their mean value A and r_c , and the difference (ΔA) and Δr_c are shown in table 2 along with AP for comparison together with other calculated values. The graph between A and r_c is obviously four different rectangular hyperbolae for four valency values.

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Table 2

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